

① Explain crystal field splitting of octahedral and square planar complexes.

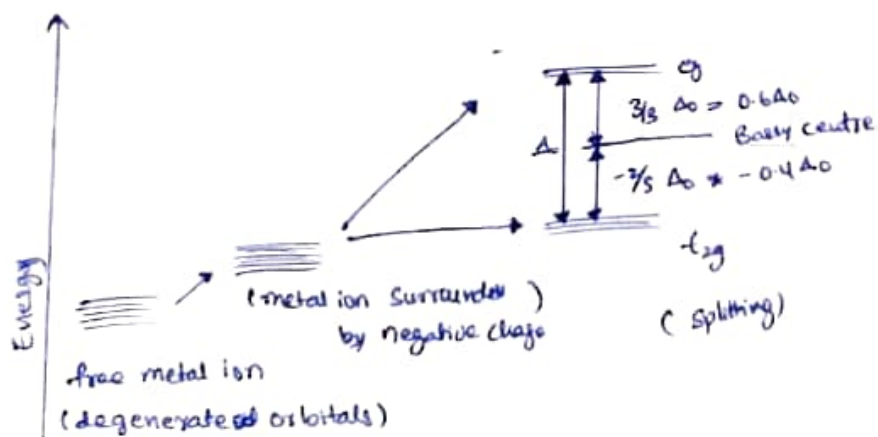
→ Octahedral Complexes:-

* In octahedral complexes, central metal ion is surrounded by six lone pairs of electrons. There are two types of electrostatic interactions in the complex.

- ① Attraction between positive metal ion and negatively charged ligand.
- ② Electrostatic repulsion b/w lone pairs in ligands and electrons in d orbitals of metal.

* Since $d_{x^2-y^2}$ and d_{z^2} orbitals are along axes, they experience much more repulsion than d_{xy} , d_{yz} , d_{zx} , which are in b/w the axes.

* As a result of these interactions, the equality in energy of five orbitals is disturbed, to give two different energy levels.



$$CFSE = [(t_{2g} \times n) + (e_g \times n)] \Delta_o$$

→ distribution of electron in complexes:

* The distribution of electrons depends on the type of ligand whether

is strong field or weak field.

for example for a d^4 electron system distribution is as follows:

d_4 (weak field):

eg \uparrow —
 t_{2g} \uparrow \uparrow \uparrow

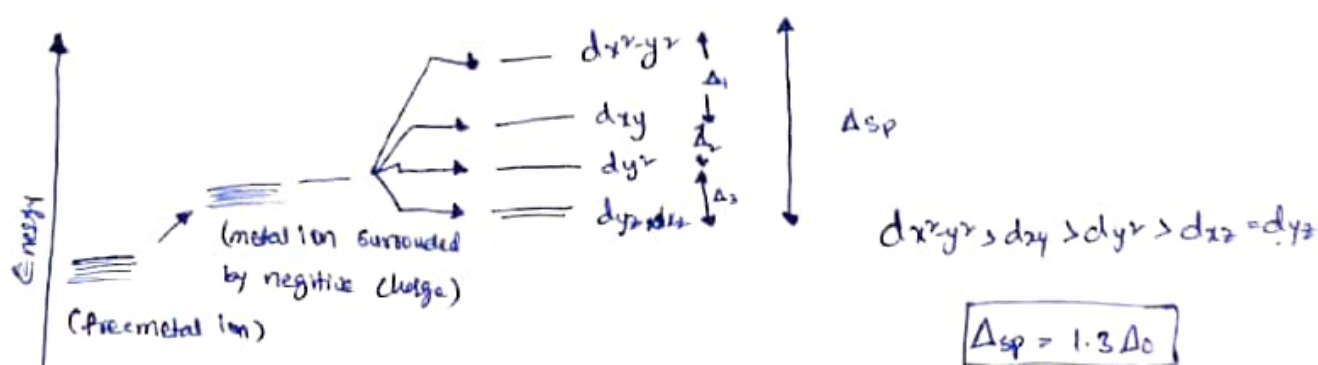
d_4 (strong field):

eg — —
 t_{2g} $\uparrow\downarrow$ \uparrow \uparrow

- * for weak field ligands - high spin (Δ_0 - less)
- * for strong field ligands - low spin (Δ_0 - more)
- * Δ_0 value depends on metal as well as ligand.
- * thus for metal, larger the size, larger is Δ_0 value.
- * larger the oxidation state of metal, larger is Δ_0 value.

SQUARE PLANAR COMPLEXES:-

- * the central metal ion is surrounded by 4 ligands
- * the greater influence on a dx^2-y^2 orbital so the energy of this orbital will be raised most
- * the d_{xy} orbital lying in same plane but between the ligands will also have greatest energy, relatively lesser than dx^2-y^2 orbital
- * dx^2 and dy^2 pair will always be affected equally and therefore remain degenerate.



→ molecular orbital theory

- * molecular orbitals are formed by the combination of atomic orbitals
- * molecular orbitals can accommodate two electrons with opposite spin
- * each and every electron in the MO belongs to all the nuclei of molecule.
- * MO is the region where electron resides. Each MO is described by a wave function ψ
- * MOs are associated with the entire molecule.
- * Conditions for overlapping of atomic orbitals:
 - Same energy
 - Same symmetry
 - Extent of overlapping between atomic orbitals.
- * the number of molecular orbitals formed is equal to the number of overlapping atomic orbitals.
- * the shape of MO depends on shape, size and orientation of atomic orbitals.
- * MOs are arranged in increasing order of their energy

types of MOs

According to LCAO, MOs are formed by addition or subtraction of wave functions of atomic orbitals.

- 1 Bonding MO
- 2 Non-Bonding MO
- 3 Anti-Bonding MO

$$BMO < NBMO < ABMO$$

Bonding MO:

$\sigma, \pi, \delta, \dots$

* formed by addition of wave function of 2o constructive interference

$$\psi_{MO} = \psi_A + \psi_B$$

* posses high electron density in region b/w nucleus and thus imparts stability to the molecule.

Anti Bonding MO:

$\sigma^*, \pi^*, \delta^*, \dots$

* formed by subtraction of wave forms of 2o, destructive influence

$$\psi_{MO}^* = \psi_A - \psi_B$$

* Posses less electron density in the region b/w nuclei

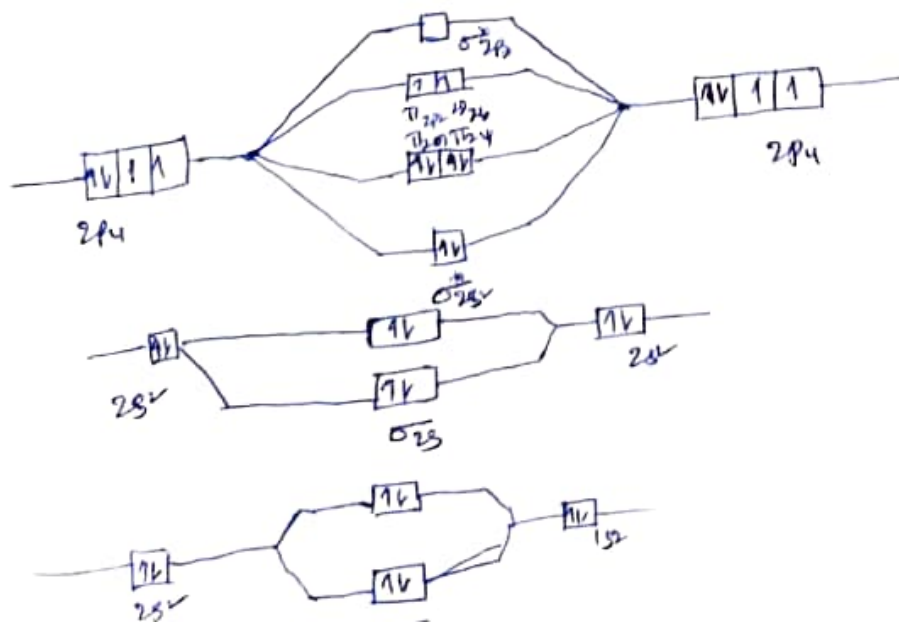
* Probability of formation of Bonding molecule orbital (

$(\psi^2) >$ Probability of formation of ABMO.

MO Energy diagrams:-

O₂ Ec: $1s^2 2s^2 2p^4$ - 2~~o~~ is the electronic configuration of O

Ec of O₂: $\sigma 1s^2 \sigma^* 1s^2 \sigma 2s^2 \sigma^* 2s^2 \sigma 2p_z^2 (\pi 2p_x^2 \pi 2p_y^2) (\pi^* 2p_x^1 \pi^* 2p_y^1)$



$$N_b = 8$$

$$N_a = 4$$

$$\therefore \text{Bond order} = \frac{1}{2} (N_b - N_a) = \frac{1}{2} (8 - 4)$$

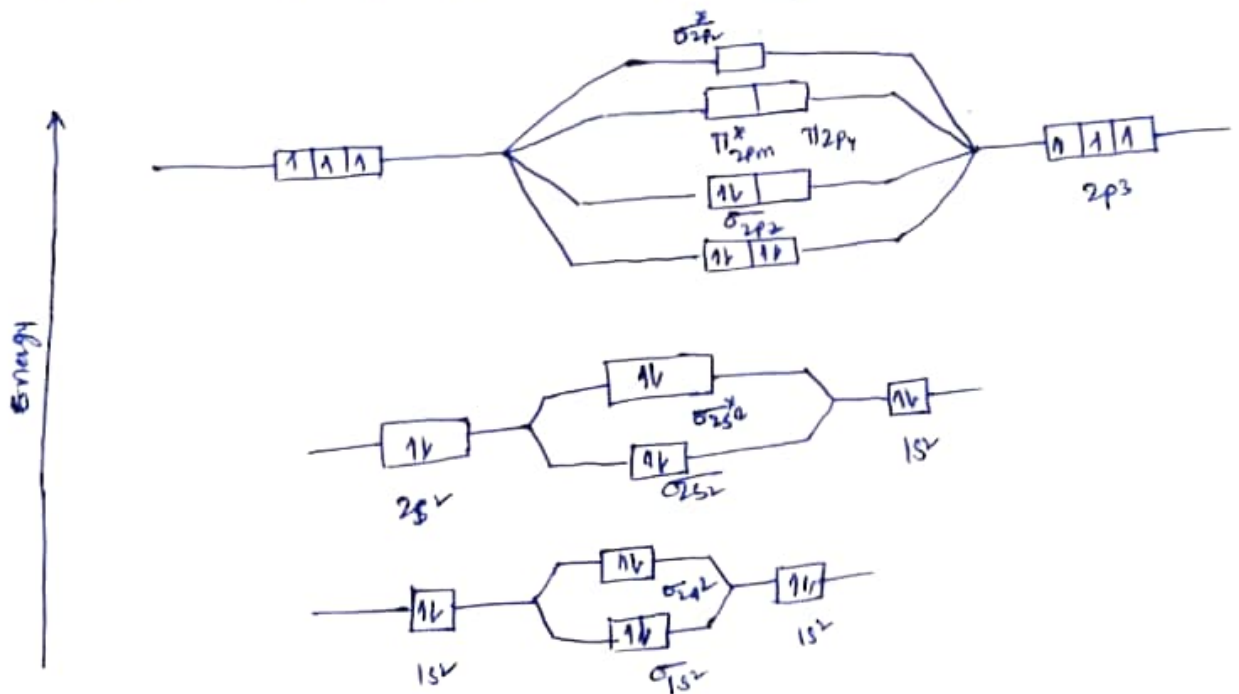
= 2, which justifies the

presence of a double bond b/w oxygen molecule (O_2)

(iii) N_2 :-

$$E_c \text{ of N: } 1s^2 2s^2 2p^3$$

$$E_c \text{ of } N_2 = \sigma_{1s}^2 \sigma_{1s}^{*2} \sigma_{2s}^2 \sigma_{2s}^{*2} (\pi_{2p}^2 = \pi_{2p}^{*2}) \sigma_{2p}^2$$



$$N_b = 10$$

$$N_a = 4$$

$$\therefore \text{Bond order} = \frac{1}{2} (10 - 4) = 3 \text{ which justifies the presence of a}$$

triple bond b/w nitrogen molecule (N_2)

Reasons for Metallic bonds

① Free electron theory:

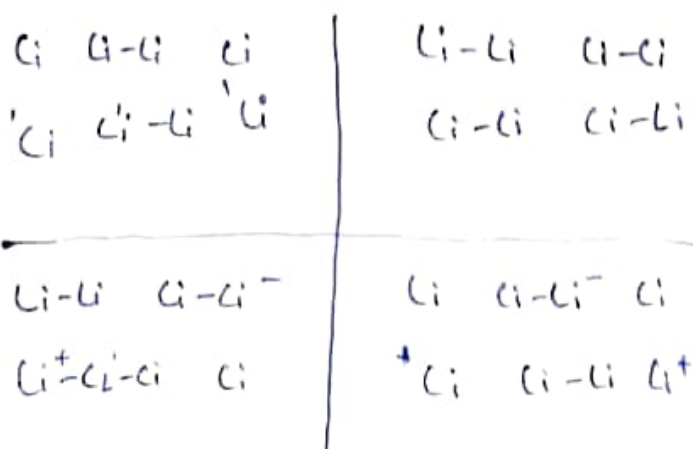
- * Positive metal ions are suspended in sea of electron
- * Attractions hold electrons near cations but not so tightly so as impede flow
- * Thus valence electrons are delocalized and don't confine to single metal.
- * This is because of decrease delocalized and don't confine restriction in metallic bond.
- * Metallic bond occurs where there is attraction between kernels and ~~decrease~~ where repulsion of electron in that gas
- * electrical conductivity, thermal conductivity, ductility, malleability is explained through electron sea model.

Limitations:

- ① Cu is 50 times better conductor than Bi
- ② metals like Al and lead are soft - it can easily cut with a knife, osmium is hard it can even scratch glass.

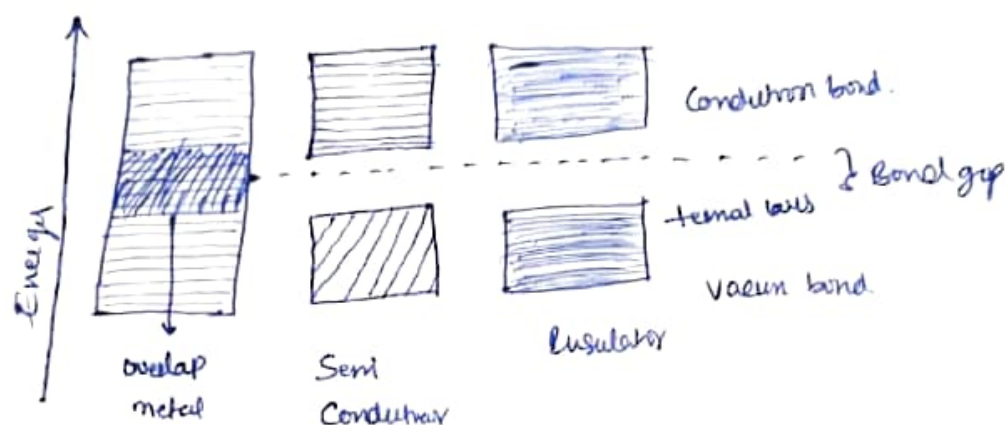
② VBT:

- * in Li metal crystal each atom is surrounded by 8 Li atoms
- * So resonance of electron pair bond takes place



Notes:

- * Most of metals Crystals is like most of covalent molecules
- * the electrons in metal are considered to belong to the crystals as a whole not to individual (or any pair of atoms).
- * metallic bond result from delocalization of free electron orbitals over all the atoms of a metal structure.



* In Li Crystal $Li-1s^2 2s^1 2p^0$

* 1s band: formed by combination of $1s^2$ orbitals as it is completely filled. It is non-conduction band.

* 2s band: 2s orbital of each Li atom has 1 electron

2s and 2p orbitals are near in energy. So 2p bands overlap with 2s band called overlapping zone.

* the level below which all energy levels are filled it termed as Fermi level.

④ LCAO:-

- * molecular orbitals can be obtained by several methods most convenient way to describe them is LCAO
- * According to LCAO, atomic orbitals can be represented by wave-function (ψ)
- * In LCAO method, the atoms are brought from a distance to equilibrium internuclear distance where the probability of formation of bond, which leads to form a molecule.
- * Consider a molecule AB formed from atoms A and B with wave-functions

ψ_A and ψ_B respectively

$$\psi_{AB} = N[C_A\psi_A + C_B\psi_B]$$

where C_A and C_B are constants used to give minimum energy for ψ_{AB}

→ N = normalizing constant

- * the probability of finding an electron in a volume of space (dv) is $\int \psi^2 dv$

$$\int_0^\infty \psi^2 dv = 1$$

- * from (1) we have two assumptions.

if $(C_A = C_B)$

$$\psi_D = N_D (A(\psi_A + \psi_B)) \dots \textcircled{2}$$

if $(C_A = -C_B)$

$$\psi_A = N_A (A(\psi_A - \psi_B)) \dots \textcircled{3}$$

- * for homonuclear diatomic molecules $C_A^2 = C_B^2$

$$\Rightarrow C_A = 1, C_B = \pm 1$$

is $C_A = 1$ & $C_B = 1$:

$$\psi_A = N_D (\psi_A + \psi_B)$$

$$16. C_A = 1 \text{ \& } C_B = -1$$

$$\psi_a = N_a (\psi_A - \psi_B)$$

* ψ^2 is probability of finding an electron

$$\psi_b^2 = \psi_A^2 + 2\psi_A\psi_B + \psi_B^2 \quad \text{--- (1)}$$

$$\psi_a^2 = \psi_A^2 - 2\psi_A\psi_B + \psi_B^2 \quad \text{--- (2)}$$

* ψ^2 is probability of finding an electron

$$\psi_b^2 = \psi_A^2 + 2\psi_A\psi_B + \psi_B^2 \quad \text{--- (1)}$$

* From (1) and (2) it is clear that finding an electron in bonding orbitals is greater than that in antibonding orbitals by an amount of $2\psi_A\psi_B$.

Rules of GAO:-

- * The AOs must roughly be of energy when considering overlap b/w too different atoms
- * For effective overlap orbitals must overlap one another as much as possible.
- * In order to produce B_0 and ABM_0 like symmetry of two AOs remain unchanged (on both AOs must change symmetry in an identical manner)

⑤ Bonding in metals:

Bonding in metals should explain the high mobility of electrons and non-directional manner of electrons

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